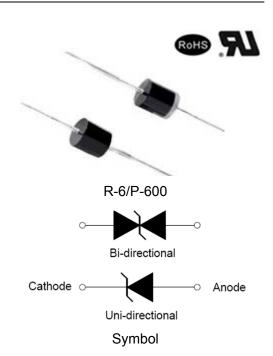


P8S Series 8000W Transient Voltage Suppressor

Rev.2.3

DESCRIPTION:

The P8S series of high current uni/bi-directional transient suppressors are designed for A.C. line protection and high power DC bus clamping applications. These devices offer uni/bi-directional port protection from 20 volts to 43 volts. They provide a clamping voltage lower than the avalanche voltage. Therefore, any voltage rise due to increased current conduction is contained to a minimum, providing the best possible protection level. They can also be connected in series and/or parallel to create very high capacity protection solutions.



FEATURES:

- Low incremental surge resistance.
- ♦ Excellent clamping capability.
- → Typical I_R less than 5µA.
- Color band denoted cathode except bidirectional.
- ♦ High temperature wave soldering: 265°C/10s at terminals.
- ♦ Plastic package has under writers laboratory flammability 94V-0.
- ♦ 8000W peak pulse power capability at 10/1000µs waveform.
- ♦ Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C.
- ♦ Terminal: solder plated, solderable per J-STD-002.
- ♦ Fast response time: typically less than 1.0ps from 0V to V_{BR} min.
- ♦ UL 497B item recognized. (File No.:E480698).
- ♦ IEC61000-4-2 (ESD) ±30kV (air), ±30kV (contact).

ABSOLUTE MAXIMUM RATINGS (TA=25°C, RH=45%-75%, unless otherwise noted)

Parameter	Symbol	Value	Unit
Operating junction and storage temperature range	T _J ,T _{STG}	-55 to +175	${\mathbb C}$
Peak pulse power dissipation at 10/1000µs waveform	P _{PP}	8000	W
Steady state power dissipation at T _L =75℃	P _{M(AV)}	8	W
Maximum instantaneous forward voltage at 100A for unidirectional	VF	5.0	V
Peak forward surge current, 8.3ms single half sine-wave for unidirectional only	İFSM	400	А



ABSOLUTE MAXIMUM RATINGS(T_A=25°C, RH=45%-75%, unless otherwise noted, continued)

Parameter	Symbol	Value	Unit
Typical thermal resistance junction to lead	R _{0JL}	8.0	°C/W
Typical thermal resistance junction to ambient	R _θ ЈА	40	°C/W

ELECTRICAL CHARACTERISTICS (T_A=25°C)

Part N	umber	V _R	Ir@Vr	V _{BR}	@ I⊤	lτ	Vc@IPP	l _{PP} ^①
Uni-Polar	Bi-Polar	V	max(µA)	min(V)	max(V)	mA	max(V)	А
P8S20A	P8S20CA	20	5	22.2	24.5	5	32.4	246.9
P8S22A	P8S22CA	22	5	24.4	26.9	5	35.5	225.3
P8S24A	P8S24CA	24	5	26.7	29.5	5	38.9	205.6
P8S26A	P8S26CA	26	5	28.9	31.9	5	42.1	190.1
P8S28A	P8S28CA	28	5	31.1	34.4	5	45.4	176.2
P8S30A	P8S30CA	30	5	33.3	36.8	5	48.4	165.3
P8S33A	P8S33CA	33	5	36.7	40.6	5	53.3	150.1
P8S36A	P8S36CA	36	5	40.0	44.2	5	58.1	137.7
P8S40A	P8S40CA	40	5	44.4	49.1	5	64.5	124.1
P8S43A	P8S43CA	43	5	47.8	52.8	5	69.4	115.3

① Surge waveform: 10/1000µs

V_R: Stand-off voltage -- Maximum voltage that can be applied

V_{BR}: Breakdown voltage

Vc: Clamping voltage -- Peak voltage measured across the suppressor at a specified IPP

I_R: Reverse leakage current



RATINGS AND V-I CHARACTERISTICS CURVES (T_A=25°C, unless otherwise noted)

FIG.1:V- I curve characteristics (Uni-directional)

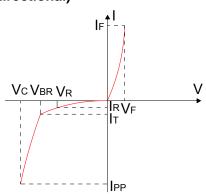


FIG.3: Pulse waveform

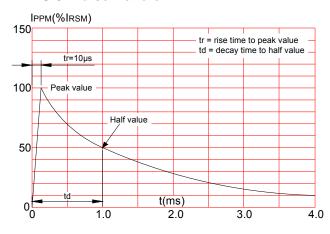


FIG.2:V- I curve characteristics (Bi-directional)

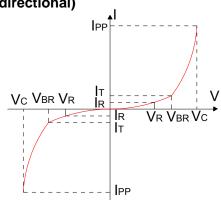
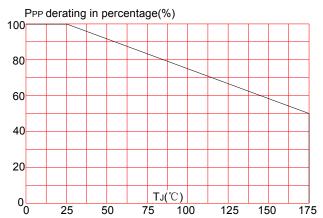
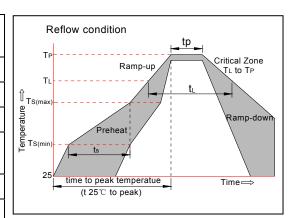


FIG.4: Pulse derating curve



SOLDERING PARAMETERS

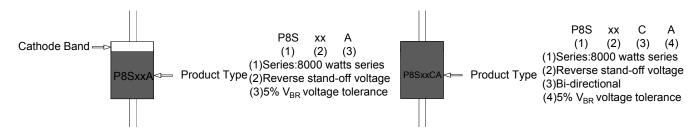
Reflow Co	ondition	Pb-Free assembly (see figure at right)	
Pre Heat	-Temperature Min (T _{s(min)})	+150℃	
	-Temperature Max(T _{s(max)})	+200℃	
	-Time (Min to Max) (ts)	60-180 secs.	
Average r (T _L)to pe	ramp up rate (Liquidus Temp eak)	3℃/sec. Max	
T _{s(max)} to T _L - Ramp-up Rate		3°C/sec. Max	
Reflow	-Temperature(T _L)(Liquidus)	+217 ℃	
	-Temperature(t∟)	60-150 secs.	
Peak Tem	np (T _p)	+260(+0/-5)°C	
Time with	in 5℃ of actual Peak Temp (t _p)	20-40secs.	
Ramp-do	wn Rate	6℃/sec. Max	
Time 25℃ to Peak Temp (T _P)		8 min. Max	
Do not exceed		+260℃	



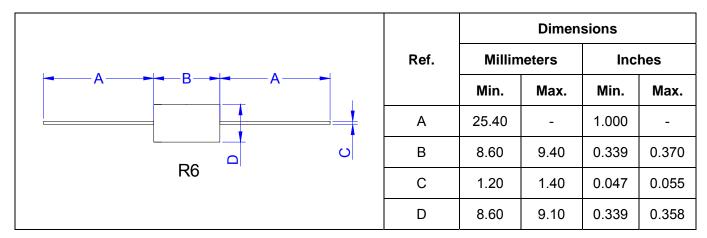
Flow/Wave Soldering(Solder Dipping)			
Peak temperature	265 ℃		
Dipping time	10 sec.		
Soldering	1 time		



MARKING & ORDERING INFORMATION



PACKAGE MECHANICAL DATA



PART No.	UNIT WEIGHT (g/PCS) typ.	PER BOX (PCS)	PER CARTON (PCS)	DESCRIPTION
P8SxxA/CA	2.5	300	3,000	Вох

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